

High Performance Schottky Rectifier, 2.1 A



SMA



FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

PRODUCT SUMMARY

Package	SMA
$I_{F(AV)}$	2.1 A
V_R	100 V
V_F at I_F	0.78 V
I_{RM}	1 mA at 125 °C
T_J max.	150 °C
Diode variation	Single die
E_{AS}	1.0 mJ

DESCRIPTION

The VS-10MQ100NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	DC	2.1	A
V_{RRM}		100	V
I_{FSM}	$t_p = 5 \mu s$ sine	120	A
V_F	1.5 A_{pk} , $T_J = 125^\circ C$	0.68	V
T_J	Range	-55 to +150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-10MQ100NPbF	UNITS
Maximum DC reverse voltage	V_R	100	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 4	$I_{F(AV)}$	50 % duty cycle at $T_L = 126^\circ C$, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)	2.1	A
Maximum peak one cycle non-repetitive surge current, $T_J = 25^\circ C$ See fig. 6	I_{FSM}	5 μs sine or 3 μs rect. pulse	120	A
		10 ms sine or 6 ms rect. pulse	30	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ C$, $I_{AS} = 0.5 A$, $L = 8 mH$	1.0	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	0.5	A

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	0.78	V
		1.5 A	0.85	
		1 A	0.63	
		1.5 A	0.68	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 125\text{ }^{\circ}\text{C}$	1	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$	0.52	V
Forward slope resistance	r_t		78.4	m Ω
Typical junction capacitance	C_T	$V_R = 10\text{ V}_{DC}$, $T_J = 25\text{ }^{\circ}\text{C}$, test signal = 1 MHz	38	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body	2.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R	10 000	V/ μ s

Note(1) Pulse width < 300 μ s, duty cycle < 2 %**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}$, T_{Stg}		-55 to +150	$^{\circ}\text{C}$
Maximum thermal resistance, junction to ambient	R_{thJA}	DC operation	80	$^{\circ}\text{C}/\text{W}$
Approximate weight			0.07	g
			0.002	oz.
Marking device		Case style SMA (similar D-64)	V1J	

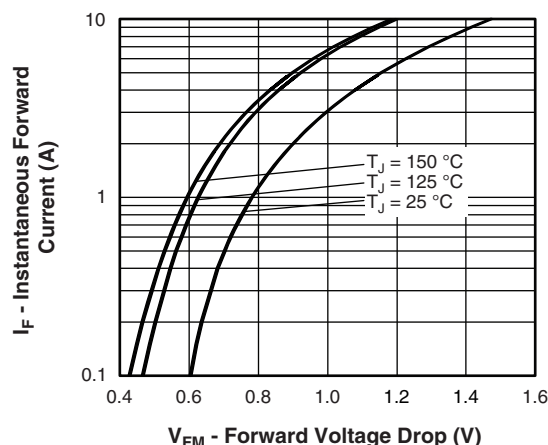
Note(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

Fig. 1 - Maximum Forward Voltage Drop Characteristics

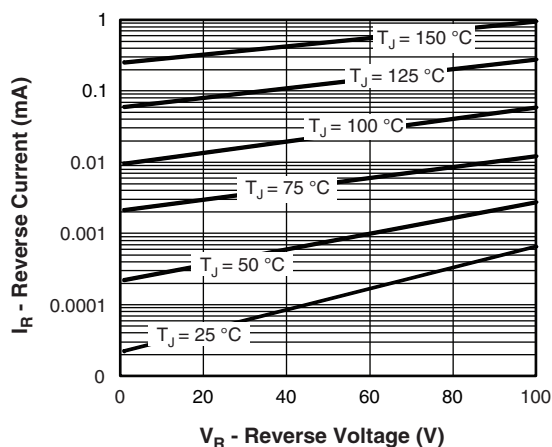


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

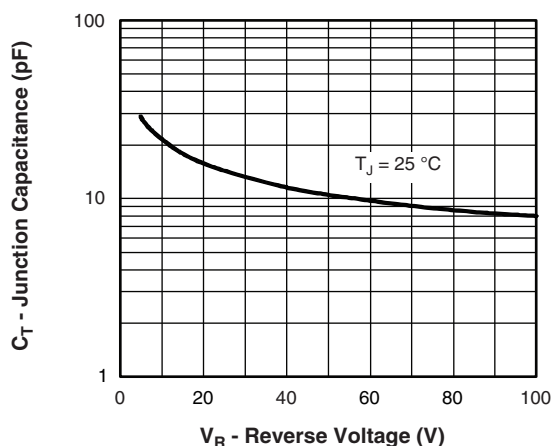


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

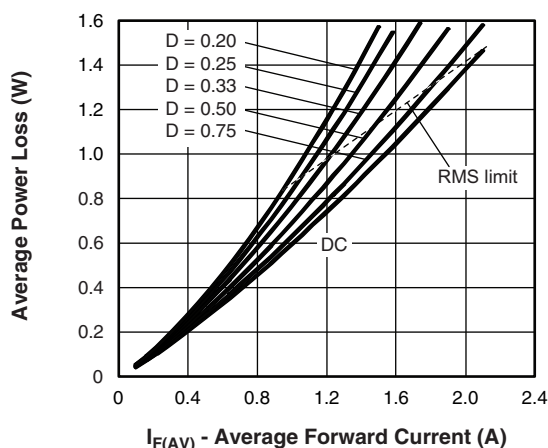


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

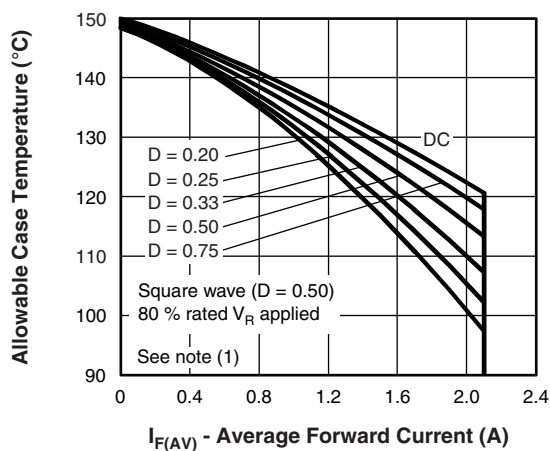


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

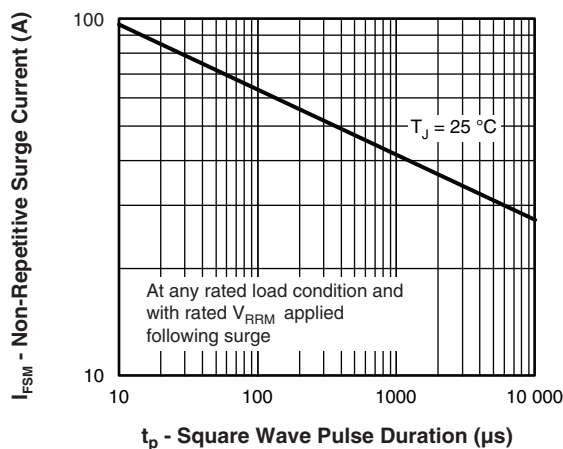


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE

Device code	VS-	10	M	Q	100	N	TR	PbF
	1	2	3	4	5	6	7	8
1	- Vishay Semiconductors product							
2	- Current rating							
3	- M = SMA							
4	- Q = Schottky "Q" series							
5	- Voltage rating (100 = 100 V)							
6	- N = new SMA							
7	- • None = box (1000 pieces) • TR = tape and reel (7500 pieces)							
8	- PbF = lead (Pb)-free							

LINKS TO RELATED DOCUMENTS		
Dimensions		www.vishay.com/doc?95018
Part marking information		www.vishay.com/doc?95029
Packaging information	Tape and reel	www.vishay.com/doc?95034
	Bulk	www.vishay.com/doc?95397
SPIICE model		www.vishay.com/doc?95371



SMA

DIMENSIONS in millimeters (inches)





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